Acta Crystallographica Section E Structure Reports Online

ISSN 1600-5368

## Anna Kropidłowska,<sup>a</sup> Ilona Turowska-Tyrk<sup>b</sup> and Barbara Becker<sup>a</sup>\*

<sup>a</sup>Department of Inorganic Chemistry, Chemical Faculty, Gdańsk University of Technology, 11/12 G. Narutowicza St., 80-952 Gdańsk, Poland, and <sup>b</sup>Institute of Physical and Theoretical Chemistry, Chemical Faculty, Wrocław University of Technology, 27 Wybrzeże Wyspiańskiego, 50-370 Wrocław, Poland

Correspondence e-mail: bbecker@chem.pg.gda.pl

#### Key indicators

Single-crystal X-ray study T = 200 KMean  $\sigma$ (C–C) = 0.004 Å R factor = 0.052 wR factor = 0.157 Data-to-parameter ratio = 10.0

For details of how these key indicators were automatically derived from the article, see http://journals.iucr.org/e.

© 2007 International Union of Crystallography All rights reserved

# 1,3-Diethyl-1,1,3,3-tetraphenyldisiloxane

Molecules of the title compound,  $C_{28}H_{30}OSi_2$ , are centrosymmetric, with the O atom lying on an inversion centre. The ethyl substituents are placed *trans* along the strictly linear Si-O-Si fragment.

Received 9 January 2007 Accepted 16 January 2007

### Comment

Crystal structures of ca 40 acyclic disiloxanes are known, but a sound explanation why their Si-O-Si angles vary within the 140-180° range still cannot be provided. The Cambridge Sructural Database (CSD, Version 5.27 of 2006 with updates; Allen, 2002) stores data for eight symmetric disiloxanes of formula  $Ph_2RSiOSiRPh_2$ ; these include R = Me (CSD refcode GIMZUX; Wojnowski et al., 1988), 'Bu (CSD refcode DEPGOU; Karle et al., 1986) and Ph [CSD refcodes OXTPSI02 (Kooijman et al., 1999) and OXTPSI10 (Glidewell & Liles, 1978)], for which the Si-O-Si angles are 140, 152.5 and  $180^{\circ}$ , respectively. We have prepared and structurally characterized 1,3-diethyl-1,1,3,3-tetraphenyldisiloxane (Ph<sub>2</sub>EtSiOSiEtPh<sub>2</sub>), (I), a compound which fits well in this series. The structure of (I) is shown in Fig. 1 and selected geometric parameters are given in Table 1.

 $\begin{array}{ccc} \mathsf{Ph} & \mathsf{Et} \\ | & | \\ \mathsf{Ph} & \mathsf{Si} & \mathsf{O} & \mathsf{Si} & \mathsf{Ph} \\ | & | \\ \mathsf{Et} & \mathsf{Ph} \\ & (\mathrm{I}) \end{array}$ 

The two halves of the molecule of (I) are related by an inversion centre located at atom O1. It follows that, despite similarities between alkyl substituents (Me, Et and 'Bu), the geometry of (I) resembles most closely that of hexaphenyldisiloxane; in both compounds (R = Et, Ph), the central Si-O-Si fragment is strictly linear. The same holds for Si-O bond lengths which are virtually the same in (I) and Ph<sub>3</sub>SiO-SiPh<sub>3</sub> [1.616 (1) Å according to Glidewell & Liles (1978), and 1.620 (1) Å determined at 150 K by Kooijman et al. (1999)], but remarkably longer in the case of Ph2MeSiOSiMePh2 [1.637 (2) and 1.640 (2) A; Wojnowski et al., 1988] and Ph<sub>2</sub><sup>t</sup>BuSiOSi<sup>t</sup>BuPh<sub>2</sub> [1.633 (1) and 1.638 (1) Å; Karle *et al.*, 1986]. These two sets of observed values correlate with the type of disiloxane structure, linear or bent, and the mutual arrangement of the alkyl substituents. Unlike Ph2EtSiO-SiEtPh<sub>2</sub>, (I), where the ethyl groups are trans, in Ph<sub>2</sub>MeSiO-SiMePh<sub>2</sub> and Ph<sub>2</sub>'BuSiOSi'BuPh<sub>2</sub> the alkyl substituents are gauche along the Si...Si axis (see Newman projections in Fig. 2). This conformation is accompanied by a bending of the Si-O-Si fragment and elongation of the Si-O bonds. The

## organic papers

same phenomenon is observed in other known disiloxanes of type  $(Ph_2RSi)_2O$  [CSD refcodes DAPNAK and DAPNOY (Nitsche *et al.*, 2003), TANKOJ (Lee *et al.*, 2002), ECOHUA and EDAFAR (Dirnens *et al.*, 2003)]; only those with *R* substituents in *trans* positions have linear Si-O-Si skeletons. The case of 1,3-bis[3-(3-pyridyl)isoxazolin-5-yl]-1,1,3,3-tetra-phenyldisiloxane (Dirnens *et al.*, 2003) is especially interesting as all three types of conformers are known for this compound. The *trans* form has a linear skeleton, but the *cis* and *gauche* forms are bent.

## Experimental

Crystals of (I) suitable for X-ray measurements were obtained by hydrolysis of a toluene solution of 1,3-diethyl-1,1,3,3-tetraphenyldisilthiane (Becker & Wojnowski, 1982) with an excess of aqueous AgNO<sub>3</sub>, followed by the usual workup and crystallization of the crude product from hexane–benzene (4:1  $\nu/\nu$ ).

Z = 2

 $D_r = 1.199 \text{ Mg m}^{-3}$ 

Mo Ka radiation

Block, colourless  $0.22 \times 0.20 \times 0.16$  mm

 $\mu = 0.16 \text{ mm}^{-1}$ 

T = 200 (2) K

#### Crystal data

 $\begin{array}{l} C_{28} \mathrm{H}_{30} \mathrm{OSi}_2 \\ M_r = 438.7 \\ \mathrm{Monoclinic}, P2_1/c \\ a = 7.8479 \ (14) \ \mathrm{\AA} \\ b = 20.603 \ (3) \ \mathrm{\AA} \\ c = 7.5978 \ (15) \ \mathrm{\AA} \\ \beta = 98.541 \ (19)^\circ \\ V = 1214.9 \ (4) \ \mathrm{\AA}^3 \end{array}$ 

#### Data collection

Kuma KM-4-CCD diffractometer  $\omega$  scans Absorption correction: none 4916 measured reflections

#### Refinement

Refinement on  $F^2$   $R[F^2 > 2\sigma(F^2)] = 0.052$   $wR(F^2) = 0.157$  S = 1.142028 reflections 203 parameters All H-atom parameters refined 2028 independent reflections 1590 reflections with  $I > 2\sigma(I)$  $R_{\text{int}} = 0.055$  $\theta_{\text{max}} = 25^{\circ}$ 

 $w = 1/[\sigma^{2}(F_{o}^{2}) + (0.0917P)^{2}]$ where  $P = (F_{o}^{2} + 2F_{c}^{2})/3$  $(\Delta/\sigma)_{max} = 0.301$  $\Delta\rho_{max} = 0.35 \text{ e} \text{ Å}^{-3}$  $\Delta\rho_{min} = -0.39 \text{ e} \text{ Å}^{-3}$ Extinction correction: *SHELXL97* Extinction coefficient: 0.023 (6)

#### Table 1

Selected geometric parameters (Å, °).

Si1-O1	1.6181 (7)	Si1-C1	1.867 (3)
Si1-C13	1.857 (3)	Si1-C7	1.870 (3)
O1-Si1-C13	109.29 (11)	Si1-O1-Si1 <sup>i</sup>	180
O1-Si1-C1	108.74 (9)	C2-C1-Si1	120.4 (2)
C13-Si1-C1	112.27 (14)	C6-C1-Si1	122.4 (2)
O1-Si1-C7	108.48 (9)	C8-C7-Si1	123.3 (2)
C13-Si1-C7	108.01 (13)	C12-C7-Si1	120.1 (2)
C1-Si1-C7	109.98 (12)	C14-C13-Si1	115.6 (2)

Symmetry code: (i) -x + 2, -y + 1, -z + 1.

All H atoms were found in an electron difference Fourier map and refined without constraints or restraints.

Data collection: CrysAlis CCD (Oxford Diffraction, 2006); cell refinement: CrysAlis RED (Oxford Diffraction, 2006); data reduction: CrysAlis RED; program(s) used to solve structure: SHELXS97



#### Figure 1

The molecular structure and atom-numbering scheme for (I), with displacement ellipsoids drawn at the 50% probability level. H atoms have been omitted for clarity. [Symmetry code: (i) -x + 2, -y + 1, -z + 1.]





(Sheldrick, 1997); program(s) used to refine structure: *SHELXL97* (Sheldrick, 1997); molecular graphics: *ORTEP-3 for Windows* (Farrugia, 1997) and *Mercury* (Macrae *et al.*, 2006); software used to prepare material for publication: *WinGX* (Farrugia, 1999).

## References

Allen, F. H. (2002). Acta Cryst. B58, 380-388.

- Becker, B. & Wojnowski, W. (1982) Synth. React. Inorg. Met. Org. Chem. 12, 565–582.
- Dirnens, V., Klusa, V., Skuyins, J., Svirskis, S., Germane, S., Kemme, A., Popelis, J. & Lukevics, E. (2003). Silicon Chem. 2, 11–25.
- Farrugia, L. J. (1997). J. Appl. Cryst. 30, 565.
- Farrugia, L. J. (1999). J. Appl. Cryst. 32, 837-838.
- Glidewell, C. & Liles, D. C. (1978). Acta Cryst. B34, 124-128.
- Karle, I. L., Karle, J. M. & Nielsen, C. J. (1986). Acta Cryst. C42, 64-67.

Kooijman, H., Spek, A. L., Nijbacker, T. & Lammertsma, K. (1999). CSD Private communication to the Cambridge Crystallographic Data Centre, 12 Union Road, Cambridge, England. reference No. CCDC 135217. Lee, Y., Yoo, K., Park, K. & Jung, O. (2002). Bull. Korean Chem. Soc. 23, 1839-1841.

Macrae, C. F., Edgington, P. R., McCabe, P., Pidcock, E., Shields, G. P., Taylor, R., Towler, M. & van de Streek, J. (2006). *J. Appl. Cryst.* **39**, 453–457. Nitsche, S. I., Weber, E., Seichter, W., Czugler, M., Palitzsch, W. & Roewer, G.

(2003). Silicon Chem. 2, 45-54.

Oxford Diffraction (2006). CrysAlis CCD and CrysAlis RED. Versions 1.171.30.5. Oxford Diffraction Ltd, Abingdon, Oxfordshire, England.

- Sheldrick, G. M. (1997). SHELXS97 and SHELXL97. University of Göttingen, Germany.
- Wojnowski, W., Becker, B., Peters, K., Peters, E. M. & von Schnering, H. G. (1988). Z. Anorg. Allg. Chem. 562, 17-22.